

# GUVA-S12GM

- Digital UVA Sensor
- Gallium Nitride Based Material
- UVA, 220 370 nm
- I2C Slave Interface, up to 400 kHz
- 13 x 13 x 3 mm, 8-pin





TCASE = 25°C

### Description

**GUVA-S12GM** is a UVA Sensor working in the spectral range of 220 – 370 nm. It contains a GaN based SMD photodiode, amplifier, ADC, digital control logic and I2C interface circuit for UV measurement, on a 13x13 mm 8-pin PCB. **GUVA-S12GM** can acquire the intensity of UVA, respectively and outputs digital count according to each intensity. By using available power management mode, the power consumption can be reduced.

### Features

- UV index measurement supported (1 ... 20)
- Programmable gain and integration time
- I2C slave interface, up to 400 kHz
- Power management modes
- Sleep current: 1 µA typical
- Supply voltage: 3.0 3.6 V

## Absolute Maximum Ratings

Parameter	Symbol	Values	Unit
Operating Temperature	$T_{CASE}$	-30 – +85	°C
Storage Temperature	T <sub>STG</sub>	-40 - +90	°C
Soldering Temperature *	T <sub>SLD</sub>	260	°C

\* must be completed within 10 seconds

## **Electro-Optical Characteristics**

Parameter	Values	Unit
Number of Output	1 (UVA)	Channel
Output Resolution	10	bits
UV Index Range	0-20	
Configurable Gain	x1 – x128	
Sleep Mode Control	Enable	
Power Management	Normal, Sleep	
I2C Clock Frequency	up to 400 kHz	
Operating Current (typical)	300	μA
Deep Sleep Current	<1	μA
Supply Voltage	3.0 - 3.6	V
Chip Size	0.23 x 0.23	mm <sup>2</sup>



## Package and Port Description

#### **Outline Dimensions**







13 x 13 x 3 mm



#### **Function Block Diagram**



#### **Application Circuit**



#### **Pin Description**

Pin Number	Pin Name	Description
1, 2	VDD	Supply Voltage
3, 4	GND	GND
5, 6	SCL	I2C clock line
7, 8	SDA	I2C data line

### Caution

ESD can damage the device hence please avoid ESD.

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